

Complex structure due to As bonding and interplay with electronic structure in superconducting BaNi₂As₂

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BaNi₂As₂ is a superconductor chemically related to the Fe-based superconductors, with a complex and poorly understood structural phase transition. We show based on first principles calculations that in fact there are two distinct competing structures. These structures are very different from electronic, transport and bonding points of view but are close in energy. These arise due to complex As bonding patterns and drive distortions of the Ni layers. This is supported by photoemission experiments. This leads to an interplay of electronic and structural behavior including induced anisotropic of the electronic transport. The competition between these distortions is associated with the complex behavior observed in BaNi₂As₂ samples.

The discovery of iron-based superconductivity [1] led to extensive activity exploring the behavior of these and related compounds. This resulted in the discovery of remarkably and unexpectedly rich behavior, including apparently distinct types of superconductivity, various manifestations of correlated electron behavior, quantum critical phenomena and strong interplays between correlated electrons and magnetism, and different symmetry breakings, including electronic nematic behavior and structural transitions [2–6]. Unraveling these interplays may be key to general understanding of high temperature superconductivity and correlated electron behavior.

Superconducting BaNi₂As₂ is a particularly interesting case [7]. BaNi₂As₂ occurs in the ideal tetragonal ThCr₂Si₂ structure at ambient temperature, similar to BaFe₂As₂ [8]. However, below ~ 130 K a lower symmetry structure is found. This low temperature structure is superconducting, with bulk fully gapped superconductivity based on specific heat measurements [9]. Sefat and co-workers, using single crystal x-ray studies classified this structure as monoclinic or triclinic, with best fit for triclinic. The resulting structure had a distortion from tetragonal in the Ni planes to form zigzag chains of Ni atoms with shorter bond lengths of ~ 2.8 Å, as compared to the interchain Ni distances of ~ 3.1 Å, and the Ni-Ni distance in the ideal tetragonal structure of 2.93 Å. This was discussed as ordering associated with Ni orbital fluctuations based on tight binding models [10]. The transition is accompanied by a very strong signature in the resistivity [11]. Photoemission measurements showed that the transition is not of magnetic character, consistent with the susceptibility data [11] and that it is strongly first order, with considerable hysteresis in band shifts [12]. This is consistent with neutron diffraction studies where a large hysteresis of ~ 10 K was found [13].

This large hysteresis is different from the transition in BaFe₂As₂, and is also different from typical charge den-

sity wave (CDW) instabilities. It is noteworthy that there is a strong suppression of this structural phase transition with P alloying in Ba(Ni_{1-x}P_x)₂As₂ with a concomitant enhancement of the superconducting critical temperature, T_c [14, 15]. However, the electronic specific heat is found to be similar for the distorted triclinic and ideal tetragonal phases, different from the expectation for a CDW [14]. Similarly, the transition can be suppressed by Sr substitution for Ba and Co substitution for Ni [16, 17]. Resistivity data for (Ba,Sr)Ni₂As₂ as a function of strain shows a nematic-like lowering of rotational symmetry from tetragonal in the transition [16]. On the other hand, an additional periodicity was observed by Lee and co-workers in the vicinity of the triclinic structure transition [18]. Interestingly, this is initially incommensurate consisting of an approximate tripling of the unit cell along one axis, but locks in at lower temperature. The x-ray data is consistent with a coexistence of the distorted phase and the ideal tetragonal structure down to low temperature [18]. Recently, this distortion was further characterized using x-ray diffraction as a coexistence of three distinct density waves with the conclusion that the observed nematicity may be from antiphase domain walls rather than an intrinsic feature of the ground state [19]. Within a theory of nematic superconductivity this suggested superconductivity emerging from domain walls, [19]. However, this may be difficult to reconcile with the observed fully gapped state from specific heat [9]. The strongly first order nature of the transition and the difficulty in establishing the detailed structure suggests more complexity in the system than a soft phonon instability related to Ni d electrons. This may include competing metastable states, which might be consistent with recent observations [19]. In any case, the detailed structure of the low temperature phase is clearly complex and not solved.

We started with first principles calculations examining

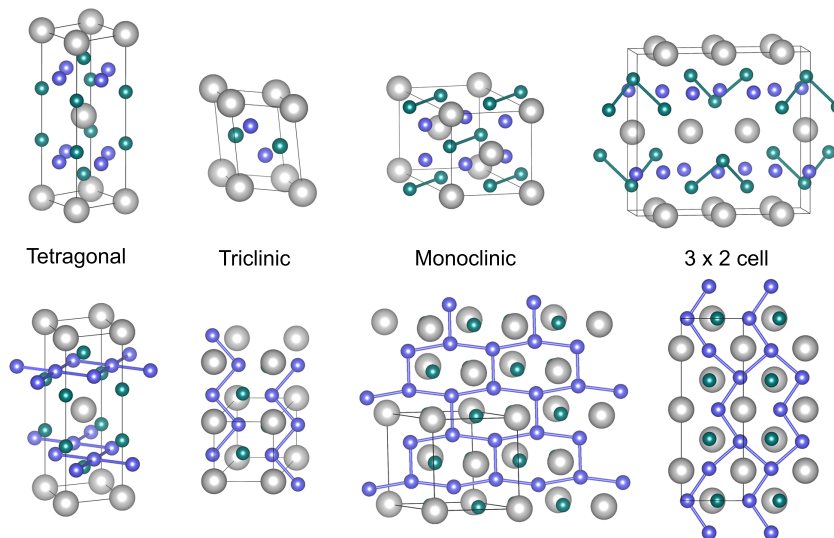


FIG. 1. Structures of BaNi_2As_2 showing the network of short As-As distances (top) and short Ni-Ni distances (bottom) in the ideal tetragonal, triclinic, based on relaxation of the structure of Sefat and co-workers [11], the monoclinic and the 3×2 structure.

TABLE I. Structural parameters after full relaxation and the corresponding calculated total energy (meV/f.u.) relative to the tetragonal structure. Results are for the PAW and LAPW methods and for the PBE and LDA functionals. Note that for the 3×2 structure, b is the direction perpendicular to the NiAs planes.

| Crystal system | Tetragonal | Monoclinic | 3×2 |
|------------------------------------|--|---|--|
| Space group | $I4/mmm$ | $C2/m$ | $Pn\bar{n}m$ |
| Lattice parameter (\AA) | $a = 4.139$ $c = 11.866$ | $a = 5.711, b = 6.540$ $c = 6.166, \gamma = 117.68^\circ$ | $a = 4.258, b = 11.533$ $c = 12.467$ |
| Atomic positions | Ba: 0.0, 0.0, 0.0 Ni: 0.0, 0.5, 0.25 As: 0.0, 0.0, 0.346 | Ba: 0.0, 0.0, 0.0 Ni: 0.5, 0.5, 0.786 As: 0.812, 0.682, 0.5 | Ba1: 0.5, 0.5, 0.0; Ba2: 0.5, 0.5, 0.664 Ni1: 0.403, 0.244, 0.5; Ni2: 0.552, 0.251, 0.176 As1: 0.546, 0.156, 0.661; As2: 0.418, 0.168, 0.0 |
| PBE (PAW/LAPW) | 0 / 0 | -18 / -23 | -21 / -26 |
| LDA (PAW/LAPW) | 0 / 0 | -32 / -37 | -39 / -46 |

the stability of the triclinic structure proposed by Sefat and co-workers [11]. These calculations were done within density functional theory (DFT) using the standard generalized gradient approximation of Perdew, Burke and Ernzerhof [20], as described below. We did calculations relaxing the atomic positions fixing the lattice parameters to the experimental triclinic values as given by Lee and co-workers [18] and also as given by Sefat and co-workers [11].

We find in both cases that while the triclinic structure, with zigzag chains of Ni atoms are maintained in the relaxation, the energy differences with respect to the tetragonal are very small and in the case of the structure of Lee and co-workers, the energy is higher than the tetragonal structure. In the case of the structure of Sefat and co-workers, the energy is lower for the relaxed triclinic structure by less than 10 meV per formula unit, which is very small considering the first order transition

at ~ 130 K. The structure highlighting the Ni-Ni chains is shown in comparison with the ideal tetragonal structure in the first two panels of Fig. 1. We also tripled the triclinic unit cell as suggested by recent experimental results and relaxed after making various small atomic displacements, but did not find any lower energy structure in these tripled cells. This in combination with the experimental results discussed above suggest that the actual structure and distortions in BaNi_2As_2 may be considerably more complex. This in fact is the case, as discussed in the results below. In particular, BaNi_2As_2 is found to have strong competing instabilities. These are associated not directly with the electronic structure of the Ni d electrons, but are driven by As-As bonding. This results in a complex interplay between the Ni d electron physics, as manifested in transport, and pnictogen bonding.

We searched for possible structures by starting with the tetragonal cell with various larger displacements of

the atoms, and then relaxing the structures. We did this in a tripled conventional cell containing six formula units (denoted 3×2 in the following). No symmetry was imposed. We used the projector augmented-wave (PAW) method [21] as implemented in VASP [22–24] and the Perdew Burke Ernzerhof generalized gradient approximation (PBE GGA) [20]. We used an energy cutoff of 550 eV and a Brillouin zone sampling with a $9 \times 9 \times 12$ mesh. We found two distinct low energy structures, with very similar energies.

The first is a monoclinic structure, with a unit cell containing a single formula unit, as depicted in Fig. 1. As seen, it is very different from the triclinic structure. In particular, it is based on a dimerization of the As ions. These displacements are coupled to the Ni layer, leading to an anisotropic arrangement of the Ni atoms to form chain-like structures as shown. This leads to a large anisotropy in the conductivity, as discussed below. The space group and structural parameters are given in Table I. The basic structural motif in tetragonal BaNi_2As_2 is square planar sheets of Ni atoms, which are tetrahedrally coordinated by As above and below the sheets.

In the PBE relaxed tetragonal structure each Ni has four Ni at 2.93 Å, and each As has one As at 3.65 Å, and four at 3.71 Å. In the triclinic structure with relaxed atomic positions and lattice parameters constrained to those of Sefat and co-workers [11], the Ni-Ni distances become two short distances of 2.77 Å, and 2.78 Å, and two longer distances of 3.13 Å, leading to zigzag chains. The As distances are also changed. The shortest As-As distance becomes 3.55 Å, while two other As come closer at ~ 3.58 Å, and two move further to ~ 3.81 Å. In contrast, the monoclinic structure that we find has a much stronger distortion of the As positions. It has a short As-As distance of 3.23 Å, with the other four nearby As in the range 3.69 Å–3.88 Å. Thus the As form dimers as shown in Fig. 1. This drives a distortion of the Ni sublattice, so that the four shortest Ni-Ni distances become 2.64 Å, 2.89 Å, 2.89 Å, and 3.53 Å. As seen in Fig. 1, this again leads to a loss of four fold rotational invariance in the Ni layers, but with a more complicated pattern than the zigzag chains.

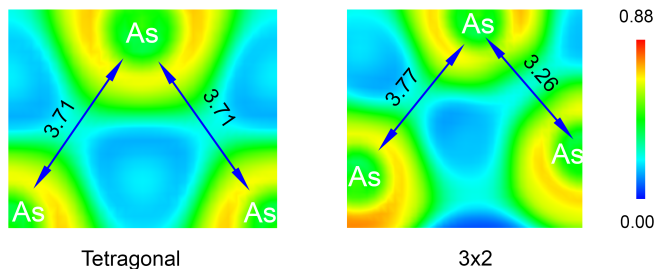


FIG. 2. Comparison of the ELF for the ideal tetragonal and 3×2 structures showing a plane containing an As trimer. The bond lengths are as indicated.

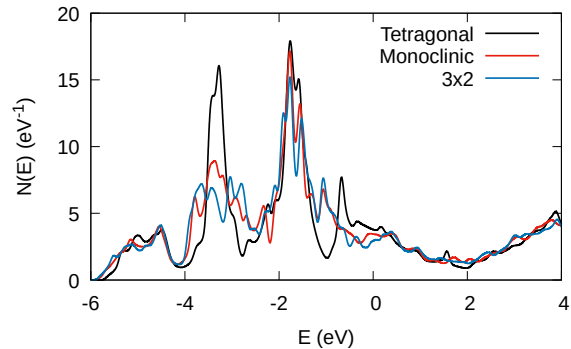


FIG. 3. Calculated electronic density of states in the tetragonal, monoclinic and 3×2 structures. The Fermi level is at zero.

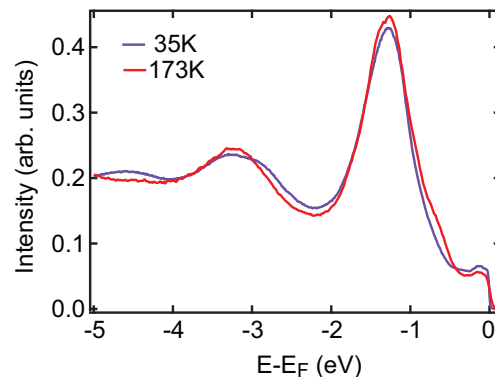


FIG. 4. Angle integrated photoemission spectra at 173 K and 35 K, i.e. in the tetragonal and low temperature structures.

The second low energy structure (the 3×2 structure) has an orthorhombic cell corresponding to the conventional cell tripled along an in-plane lattice direction. It has spacegroup $Pnmm$. Similar to the monoclinic structure, it is based on strong distortion of the As framework, which drives a distortion of the Ni sublattice, as shown in Fig. 1. Structural parameters are in Table I. The nature of the distortion is, however, very different from the monoclinic structure. It may be described as a trimer-

TABLE II. Total density of states (electrons/f.u.) at Fermi level $N(E_F)$ and σ/τ ($10^{20}/\Omega\text{ms}$) for the tetragonal, monoclinic and 3×2 structures. For the monoclinic structure the eigenvalues of the σ/τ tensor are given. For the 3×2 structure, the first two values are the in plane short and long directions and the final value is the c -axis direction perpendicular to the NiAs layers.

| Phase | $N(E_F)$ | σ_x/τ | σ_y/τ | σ_z/τ |
|--------------|----------|-----------------|-----------------|-----------------|
| Tetragonal | 3.78 | 4.98 | 4.98 | 1.65 |
| Monoclinic | 3.45 | 4.31 | 3.83 | 1.30 |
| 3×2 | 2.94 | 2.08 | 0.56 | 0.57 |

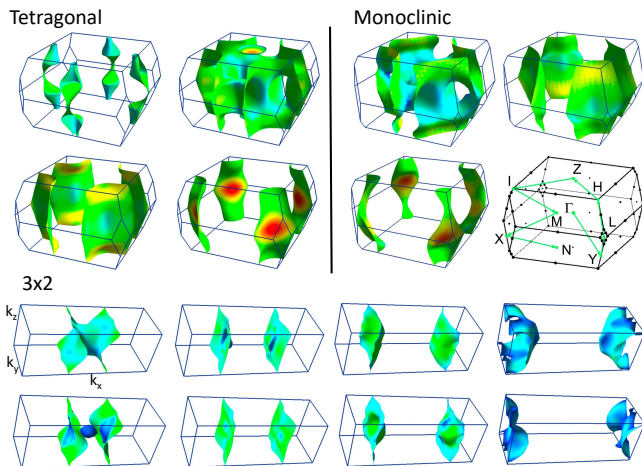


FIG. 5. Fermi surfaces colored by velocity in the tetragonal, monoclinic and 3×2 structures. Also shown is the Brillouin zone for the monoclinic structure. Blue is low velocity and red is high.

ization of the As yielding bent As_3 units instead of the dimers characterizing the monoclinic structure. These are stacked oppositely along the c -axis direction, leading to a six formula unit cell. The As-As bond lengths in the trimers are 3.26 Å. The other As-As distances range from 3.62 Å to 3.94 Å. Fig. 2 shows a comparison of the electron localization function (ELF) [25] in the plane of one of the trimers with a similar plane in the ideal tetragonal structure. The ELF shows bonding interactions between the As atoms making up a trimer. Similar to the monoclinic structure this distortion of the As sublattice drives a reconstruction of the Ni sublattice, again leading to a clear visible loss of four fold rotational symmetry. The Ni-Ni distances, all equal in the ideal tetragonal structure, are in the range 2.65 Å–3.53 Å, demonstrating a very large distortion.

We checked these results by further relaxing internal coordinates and calculating the energies using the linearized augmented planewave method as implemented in WIEN2k [26], but did not find any significant differences. We also did calculations using the local density approximation (LDA), but again find similar structures. Details are in Table I. The 3×2 structure has the lowest energy. Importantly, it and the monoclinic have similar energies, and these significantly lower than either the ideal tetragonal or the triclinic structures.

We now turn to the electronic structure. The distortions strongly affect the electronic structure, including near the Fermi level, where the states are mainly Ni d derived. The electronic densities of states (DOS) of the two low energy structures are compared with the ideal tetragonal structure in Fig. 3. As seen there is a considerable reconstruction of the DOS, including the region near the Fermi level, E_F where the states are primarily Ni d derived. This is reflected in the values at the Fermi

level, $N(E_F)$ as given in Table II. There are also substantial changes in the DOS near ~ -1 eV and ~ -3.4 eV.

We additionally did angle integrated photoemission spectroscopy to probe the DOS in the tetragonal and lower symmetry distorted structure. The result is as shown in Fig. 4. High-quality single crystals of BaNi_2As_2 were synthesized using the self-flux method. Angle-integrated photoemission spectroscopy were performed using a DA30L analyzer and helium discharge lamp with a typical energy resolution of 12 meV. The samples were cleaved in-situ with a base pressure below 510^{11} torr. A prominent peak appears in the measured DOS at approximately -1.3 eV, while two broader peaks are located at ~ -3 eV and ~ -4.5 eV. The overall structure is reasonably consistent with the calculated DOS. When temperature is lowered across the structural transition, the ~ -3 eV peak appears to broaden. This is also consistent with the overall trend in the calculated DOS from the tetragonal phase to the lower symmetry phase.

The Fermi surfaces are strongly affected by the transition. The tetragonal structure has four sheets of Fermi surface as seen. The monoclinic has only three sheets, with a noticeable anisotropy. This is quantified by the transport function σ/τ as given in Table II. This was obtained using the BoltzTraP code [27]. Larger changes in the Fermi surfaces and transport function are found in the 3×2 structure. The zone folding associated with the formation of the six formula unit cell leads to eight bands crossing the Fermi energy. Importantly, while the in-plane conductivity is reduced in both directions, it is very strongly reduced in direction of the unit tripling. This leads to a prediction of a very strong transport anisotropy.

The characteristic of the two distortions that we find is a formation of dimers or trimers of As. The results imply rebonding of the As as an important ingredient in understanding the structural distortions of BaNi_2As_2 . The formation of the electronic structure of AB_2X_2 ThCr $_2$ Si $_2$ -type materials is known to depend on both B - X and X - X bonding, which can vary between compounds [28]. Here we find that, as in the electronic structure, the structural stability and distortions of BaNi_2As_2 are governed by both Ni-As and As-As interactions. This illustrates a fundamental difference between the physics of correlated transition metal oxides and correlated pnictide metals. Oxygen anions do not normally bond in transition metal oxides compounds. This is a consequence of the relatively small effective size of O^{2-} and the high electronegativity of O. As a result structural instabilities in oxides are normally a consequence of instabilities associated with steric effects, for example mismatches of ionic radii in perovskites and d electrons physics, particularly Fermi surface instabilities, orbital orderings and the interplay of structure with Mott physics. However, other chalcogenides, particularly tellurides can have structures driven

by chalcogen-chalcogen bonding. This is because of the lower electronegativity and larger size of Te anions, as seen for example in the first order structural phase transition of IrTe₂ [29, 30]. Here we find an interplay between the *d* electron physics and the structure with distortions related to As bonding. The present results show the importance of these effects in the physics of BaNi₂As₂.

To summarize, we find that the structural instability of BaNi₂As₂ is related to rebonding of the As anions, which then drives reconstruction of the electronic structure. We find low energy structures related to the formation of As dimers and trimers. Other structures with more complex bonding arrangements of the As may occur. It is likely that the competition between structures underlies the complex structural and electronic behavior observed in BaNi₂As₂. There is a strong interplay of these bonding arrangements with the Ni derived electronic structure, including strong changes in the Fermiology and transport function. This may provide novel routes to modify and control the electronic properties of correlated metals and exploring the physics of such systems.

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